Discrete IGBTs Silicon N-Channel IGBT

GT30N135SRA

1. Applications (Note)

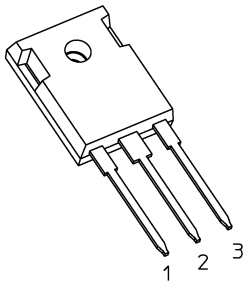
- Dedicated to Voltage-Resonant Inverter Switching Applications
- Dedicated to Soft Switching Applications
- Dedicated to Induction Cooktops and Home Appliance Applications

Note: The product(s) described herein should not be used for any other application.

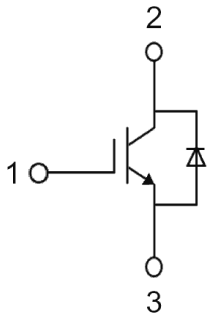
2. Features

(1) 6.5th generation
(2) The RC-IGBT consists of a freewheeling diode (FWD) monolithically integrated in an IGBT chip.
(3) Enhancement mode
(4) High-speed switching:
IGBT t_f = 0.25 μs (typ.) (I_C = 60 A)
(5) Low saturation voltage: $V_{CE(sat)}$ = 1.65 V (typ.) (I_C = 30 A, T_a = 25 °C)
(6) High junction temperature: T_j = 175 °C (max)

3. Packaging and Internal Circuit



TO-247



1: Gate
2: Collector(Heatsink)
3: Emitter

Start of commercial production
2021-07

©2026
Toshiba Electronic Devices & Storage Corporation

4. Absolute Maximum Ratings (Note) (T_a = 25 °C, unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Collector-emitter voltage		(Note 2)	V_{CES}	1350	V
Gate-emitter voltage			V_{GES}	±25	V
Collector current (DC)	(T_c = 25 °C)		I_C	60	A
Collector current (DC)	(T_c = 100 °C)			30	
Collector current (1 ms)			I_{CP}	120	A
Non-repetitive peak collector current		(Note 1)	I_{CSM}	260	A
Diode forward current (DC)	(T_c = 25 °C)		I_F	60	A
Diode forward current (DC)	(T_c = 100 °C)			30	
Diode forward current (100 μs)			I_{FP}	120	A
Collector power dissipation	(T_c = 25 °C)		P_C	348	W
Junction temperature		(Note 2)	T_j	175	°C
Storage temperature			T_{stg}	-55 to 175	°C
Mounting torque			TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

In general, loss of IGBT increases more when it has positive temperature coefficient and gets higher temperature.
In case that the temperature rise due to loss of IGBT exceeds the heat release capacity of a device, it leads to thermorunaway and results in destruction.
Therefore, please design heat release of a device with due consideration to the temperature rise of IGBT.

Note 1: The maximum value of the capacitor charging current limited on T_j < 175 °C and t < 3 μs

Note 2: To perform derating ensures the device reliability.
In operation, the collector emitter voltage(V_{CES}) should be below 1150 V, as well as junction temperature(T_j) should be below 140 °C.

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Junction-to-case thermal resistance	$R_{th(j-c)}$	0.43	°C/W

©2026
Toshiba Electronic Devices & Storage Corporation

6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25 °C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GES}	V_{GE} = ±25 V, V_{CE} = 0 V	—	—	±100	nA
Collector cut-off current	I_{CES}	V_{CE} = 1350 V, V_{GE} = 0 V	—	—	100	μA
Collector-emitter breakdown voltage	$V_{(BR)CES}$	I_C = 0.5 mA, V_{GE} = 0 V	1350	—	—	V
Gate-emitter cut-off voltage	$V_{GE(OFF)}$	I_C = 60 mA, V_{CE} = 5 V	5.3	—	7.3	V
Collector-emitter saturation voltage	$V_{CE(sat)(1)}$	I_C = 30 A, V_{GE} = 15 V (pulse test)	—	1.65	1.95	V
	$V_{CE(sat)(2)}$	I_C = 30 A, V_{GE} = 15 V, T_c = 125 °C (pulse test)	—	1.90	—	
	$V_{CE(sat)(3)}$	I_C = 60 A, V_{GE} = 15 V (pulse test)	—	2.15	2.60	
	$V_{CE(sat)(4)}$	I_C = 60 A, V_{GE} = 15 V, T_c = 125 °C (pulse test)	—	2.60	—	
Diode forward voltage	$V_{F(1)}$	I_F = 30 A, V_{GE} = 0 V (pulse test)	—	1.75	2.40	V
	$V_{F(2)}$	I_F = 30 A, V_{GE} = 0 V, T_c = 125 °C (pulse test)	—	1.85	—	

©2026
Toshiba Electronic Devices & Storage Corporation

6.2. Dynamic Characteristics (T_a = 25 °C, unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{ies}	V_{CE} = 25 V, V_{GE} = 0 V, f = 100 kHz	—	3700	—	pF
Reverse transfer capacitance	C_{res}		—	40	—	
Output capacitance	C_{oes}		—	55	—	
Total gate charge	Q_g	V_{CC} = 600 V, I_C = 60 A, V_{GE} = 15 V	—	270	—	nC
Switching time (rise time)	t_r	Resistive load V_{CC} = 600 V, I_C = 60 A, V_{GE} = 15 V/0 V, R_G = 10 Ω Duty ≤ 1 % T_c = 25 °C See Fig. 6.2.1, 6.2.2	—	0.14	—	μs
Switching time (turn-on time)	t_{on}		—	0.21	—	
Switching time (fall time)	t_f		—	0.25	0.35	
Switching time (turn-off time)	t_{off}		—	0.50	—	
Switching loss (turn-off switching loss)	$E_{off(1)}$	V_{CC} = 300 V, I_C = 60 A, V_{GE} = 15 V/0 V, R_G = 39 Ω L = 30 μH, C = 0.33 μF Duty ≤ 1 % T_c = 25 °C See Fig. 6.2.3, 6.2.4	—	0.80	—	mJ
	$E_{off(2)}$	V_{CC} = 300 V, I_C = 60 A, V_{GE} = 15 V/0 V, R_G = 39 Ω, L = 30 μH, C = 0.33 μF Duty ≤ 1 % T_c = 125 °C See Fig. 6.2.3, 6.2.4	—	1.30	—	

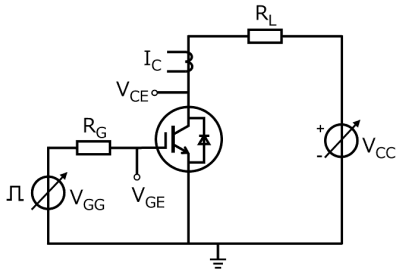


Fig. 6.2.1 Test Circuit of Switching Time

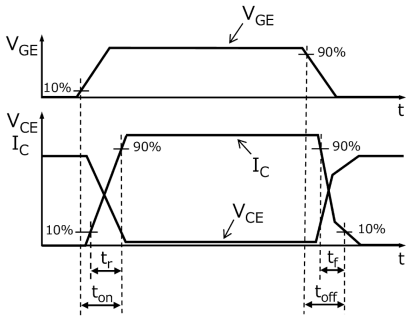


Fig. 6.2.2 Timing Chart of Switching Time

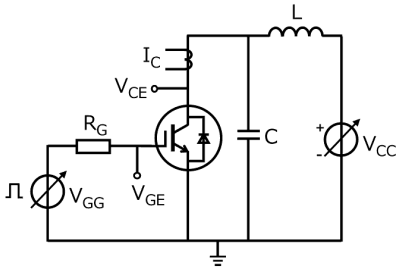


Fig. 6.2.3 Test Circuit of Switching Loss

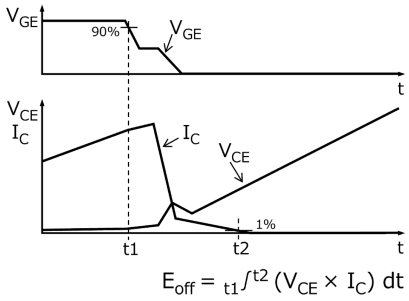


Fig. 6.2.4 Timing Chart of Switching Loss

7. Marking (Note)

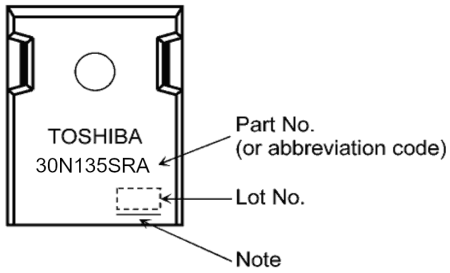


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

©2026
Toshiba Electronic Devices & Storage Corporation

8. Characteristics Curves (Note)

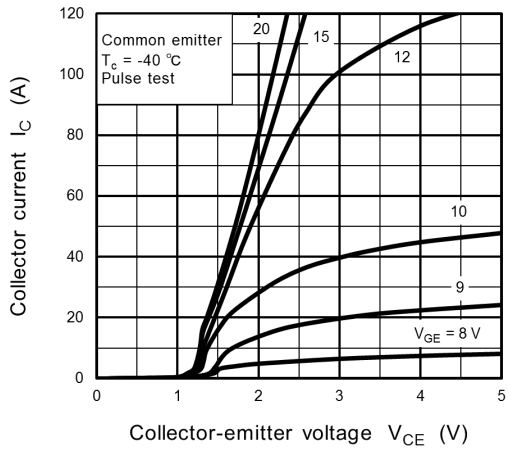


Fig. 8.1 I_C - V_{CE}

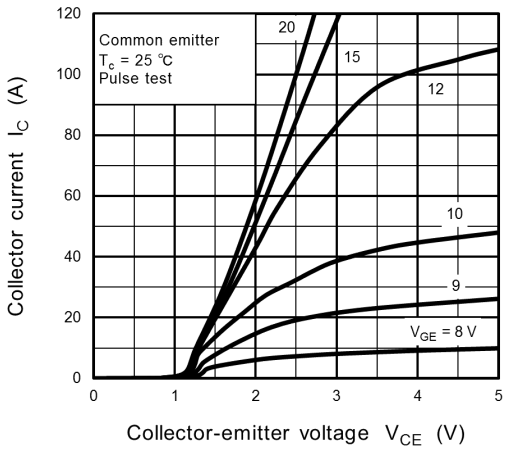


Fig. 8.2 I_C - V_{CE}

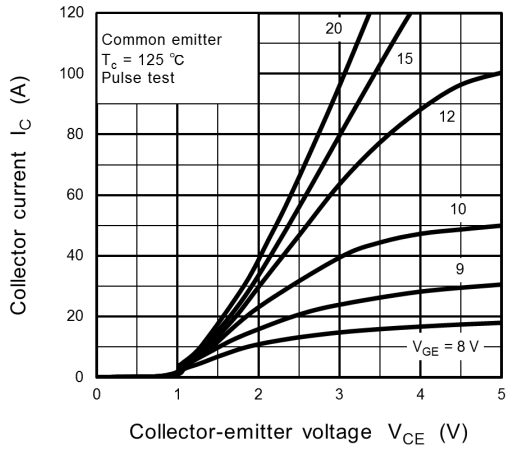


Fig. 8.3 I_C - V_{CE}

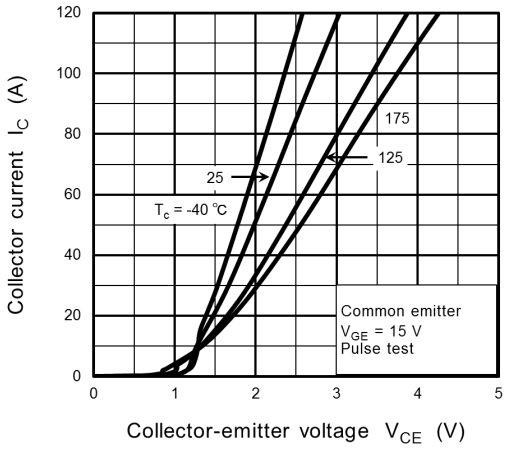


Fig. 8.4 I_C - V_{CE}

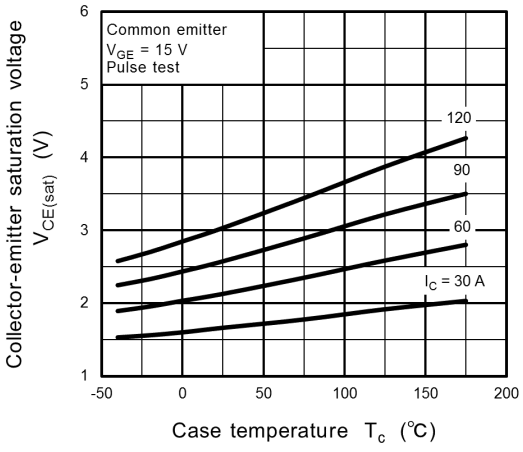


Fig. 8.5 $V_{CE(sat)}$ - T_c

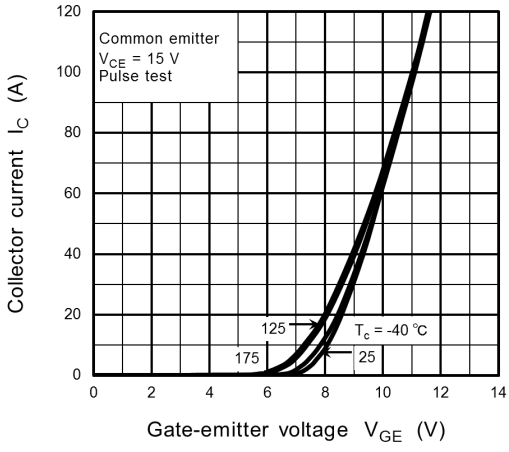


Fig. 8.6 I_C - V_{GE}

©2026
Toshiba Electronic Devices & Storage Corporation

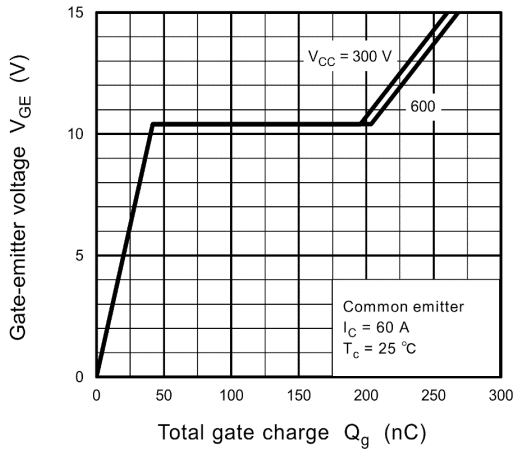


Fig. 8.7 V_{GE} - Q_g

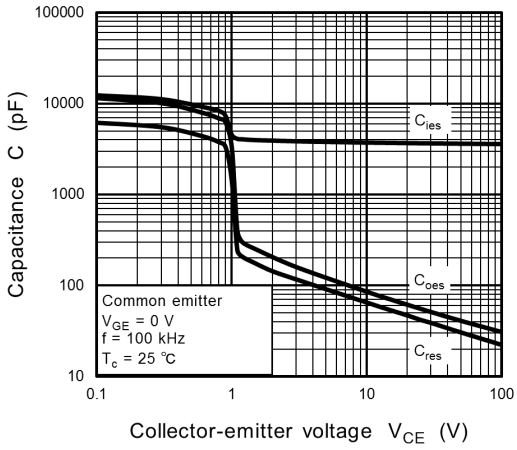


Fig. 8.8 C -V_{CE}

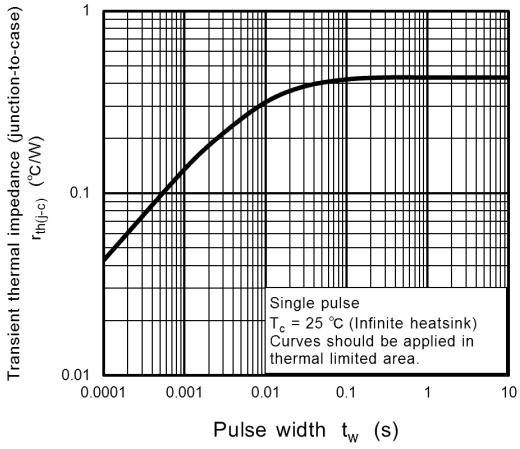


Fig. 8.9 $r_{th(j-c)}$ - t_w (Guaranteed Maximum)

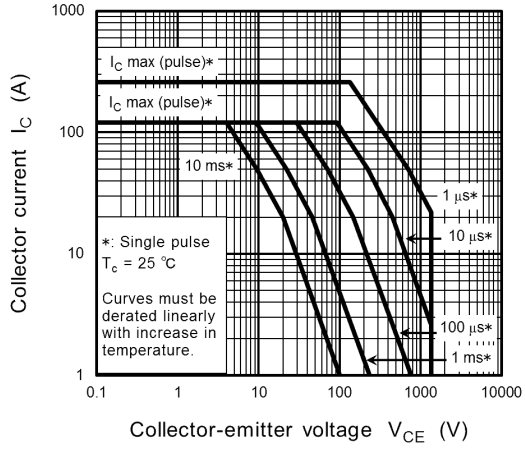


Fig. 8.10 Safe Operating Area (Guaranteed Maximum)

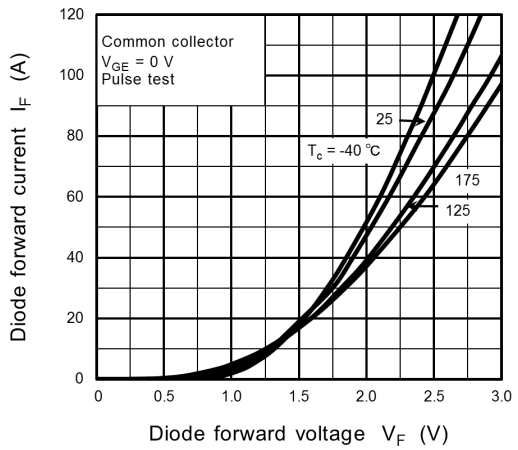


Fig. 8.11 I_F - V_F

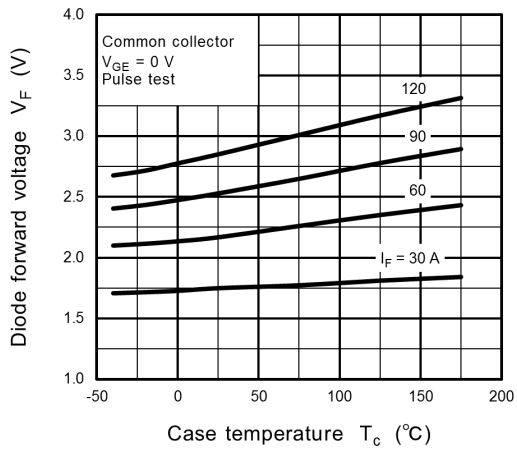


Fig. 8.12 V_F - T_c

©2026
Toshiba Electronic Devices & Storage Corporation

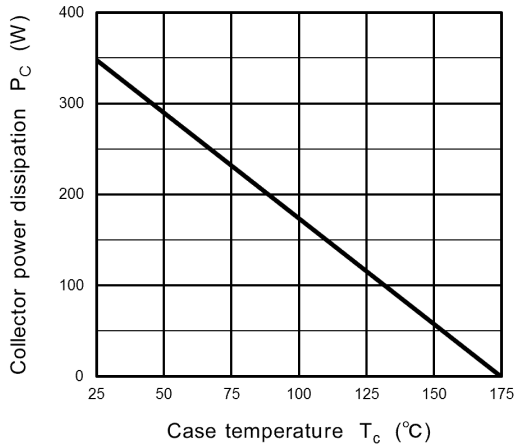


Fig. 8.13 P_C - T_c

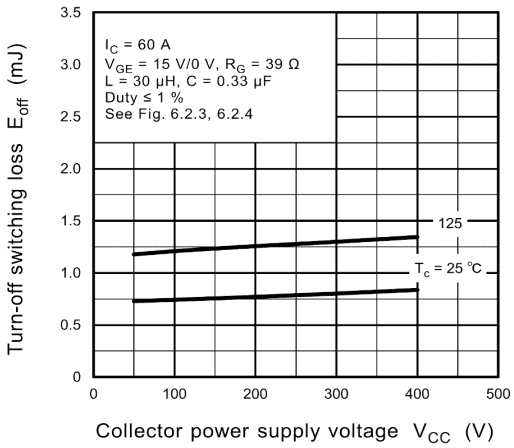


Fig. 8.14 E_{off} - V_{CC}

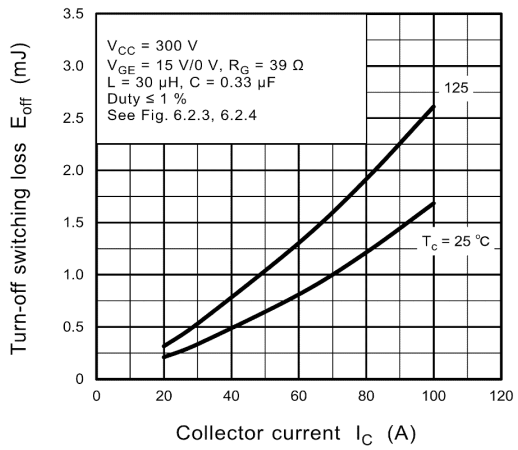


Fig. 8.15 E_{off} - I_C

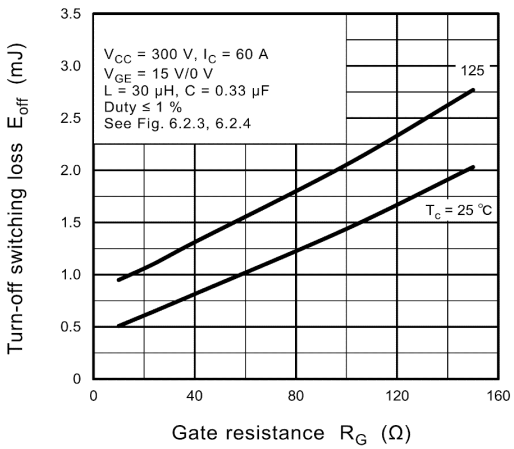


Fig. 8.16 E_{off} - R_G

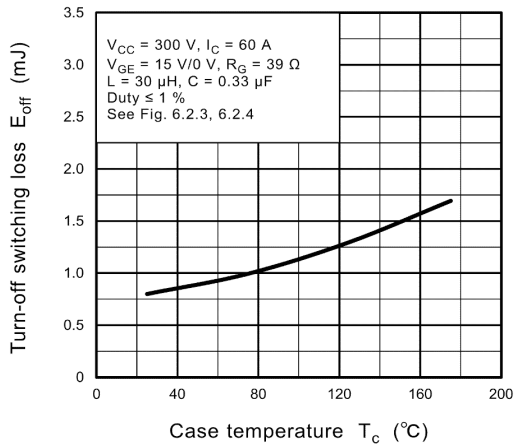


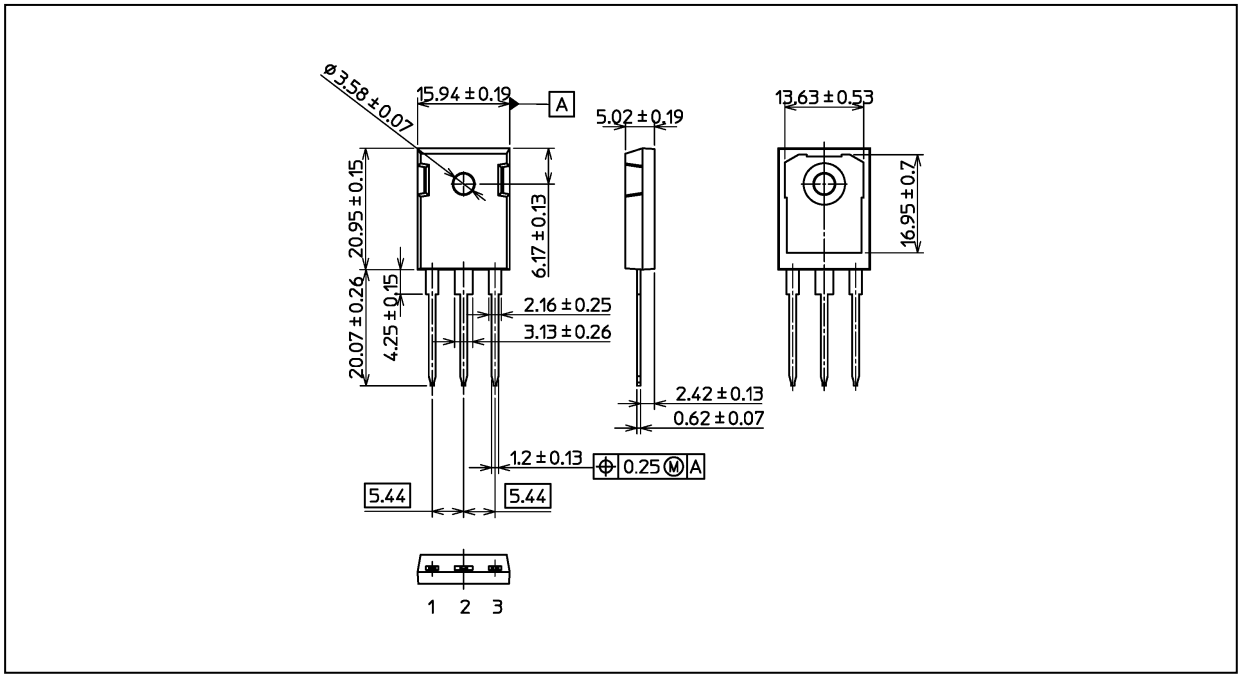
Fig. 8.17 E_{off} - T_c

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

©2026
Toshiba Electronic Devices & Storage Corporation

Package Dimensions

Unit: mm



Weight: 6.15 g (typ.)

Package Name(s)
TOSHIBA: 2-16L1A
Nickname: TO-247

RESTRICTIONS ON PRODUCT USE

Toshiba Corporation and its subsidiaries and affiliates are collectively referred to as "TOSHIBA".
Hardware, software and systems described in this document are collectively referred to as "Product".

- TOSHIBA reserves the right to make changes to the information in this document and related Product without notice.
- This document and any information herein may not be reproduced without prior written permission from TOSHIBA. Even with TOSHIBA's written permission, reproduction is permissible only if reproduction is without alteration/omission.
- Though TOSHIBA works continually to improve Product's quality and reliability, Product can malfunction or fail. Customers are responsible for complying with safety standards and for providing adequate designs and safeguards for their hardware, software and systems which minimize risk and avoid situations in which a malfunction or failure of Product could cause loss of human life, bodily injury or damage to property, including data loss or corruption. Before customers use the Product, create designs including the Product, or incorporate the Product into their own applications, customers must also refer to and comply with (a) the latest versions of all relevant TOSHIBA information, including without limitation, this document, the specifications, the data sheets and application notes for Product and the precautions and conditions set forth in the "TOSHIBA Semiconductor Reliability Handbook" and (b) the instructions for the application with which the Product will be used with or for. Customers are solely responsible for all aspects of their own product design or applications, including but not limited to (a) determining the appropriateness of the use of this Product in such design or applications; (b) evaluating and determining the applicability of any information contained in this document, or in charts, diagrams, programs, algorithms, sample application circuits, or any other referenced documents; and (c) validating all operating parameters for such designs and applications. **TOSHIBA ASSUMES NO LIABILITY FOR CUSTOMERS' PRODUCT DESIGN OR APPLICATIONS.**
- **PRODUCT IS NEITHER INTENDED NOR WARRANTED FOR USE IN EQUIPMENTS OR SYSTEMS THAT REQUIRE EXTRAORDINARILY HIGH LEVELS OF QUALITY AND/OR RELIABILITY, AND/OR A MALFUNCTION OR FAILURE OF WHICH MAY CAUSE LOSS OF HUMAN LIFE, BODILY INJURY, SERIOUS PROPERTY DAMAGE AND/OR SERIOUS PUBLIC IMPACT ("UNINTENDED USE").** Except for specific applications as expressly stated in this document, Unintended Use includes, without limitation, equipment used in nuclear facilities, equipment used in the aerospace industry, Class 3 medical devices, equipment used for automobiles, and military vehicles and munitions. **IF YOU USE PRODUCT FOR UNINTENDED USE, TOSHIBA ASSUMES NO LIABILITY FOR PRODUCT.** For details, please contact your TOSHIBA sales representative or contact us via our website.
- Do not disassemble, analyze, reverse-engineer, alter, modify, translate or copy Product, whether in whole or in part.
- Product shall not be used for or incorporated into any products or systems whose manufacture, use, or sale is prohibited under any applicable laws or regulations.
- The information contained herein is presented only as guidance for Product use. No responsibility is assumed by TOSHIBA for any infringement of patents or any other intellectual property rights of third parties that may result from the use of Product. No license to any intellectual property right is granted by this document, whether express or implied, by estoppel or otherwise.
- **ABSENT A WRITTEN SIGNED AGREEMENT, EXCEPT AS PROVIDED IN THE RELEVANT TERMS AND CONDITIONS OF SALE FOR PRODUCT, AND TO THE MAXIMUM EXTENT ALLOWABLE BY LAW, TOSHIBA (1) ASSUMES NO LIABILITY WHATSOEVER, INCLUDING WITHOUT LIMITATION, INDIRECT, CONSEQUENTIAL, SPECIAL, OR INCIDENTAL DAMAGES OR LOSS, INCLUDING WITHOUT LIMITATION, LOSS OF PROFITS, LOSS OF OPPORTUNITIES, BUSINESS INTERRUPTION AND LOSS OF DATA, AND (2) DISCLAIMS ANY AND ALL EXPRESS OR IMPLIED WARRANTIES AND CONDITIONS RELATED TO SALE, USE OF PRODUCT, OR INFORMATION, INCLUDING WARRANTIES OR CONDITIONS OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, ACCURACY OF INFORMATION, OR NONINFRINGEMENT.**
- Do not use or otherwise make available Product or related software or technology for any military purposes, including without limitation, for the design, development, use, stockpiling or manufacturing of nuclear, chemical, or biological weapons or missile technology products (mass destruction weapons). Product and related software and technology may be controlled under the applicable export laws and regulations including, without limitation, the Japanese Foreign Exchange and Foreign Trade Law and the U.S. Export Administration Regulations. Export and re-export of Product or related software or technology are strictly prohibited except in compliance with all applicable export laws and regulations.
- Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. Please use Product in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances, including without limitation, the EU RoHS Directive. **TOSHIBA ASSUMES NO LIABILITY FOR DAMAGES OR LOSSES OCCURRING AS A RESULT OF NONCOMPLIANCE WITH APPLICABLE LAWS AND REGULATIONS.**

©2026
Toshiba Electronic Devices & Storage Corporation

ENTEGRECİ

Bu belge www.entegreci.com üzerinden sunulmaktadır.

Elektronik komponent tedarikinde Entegreci

Entegreci, Eskişehir merkezli, Türkiye geneline satış yapan bir elektronik komponent mağazasıdır. Entegreler (IC), mikrodenetleyiciler, transistörler, diyotlar, pasif elemanlar, konnektörler, modüller ve geliştirme kartları tek adetten seri üretim adetlerine kadar satılır. Ürün sayfalarında güncel stok durumunu, fiyatı ve datasheet bağlantısını bulabilirsiniz.

Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

Bu sayfa Entegreci tarafından eklenmiştir. Belgenin önceki sayfaları asıl yayıncısına aittir ve içeriği değiştirilmemiştir; en güncel sürüm için belgenin yayıncısına başvurun.